



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

0755-83047638

ysbdt@szyoushang.cn

www.szyoushang.cn



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Features

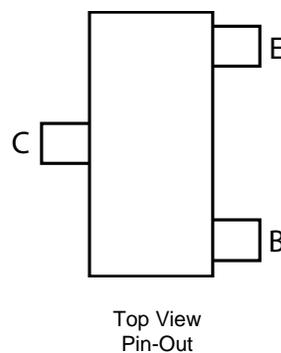
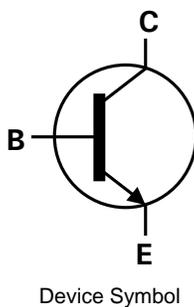
- $BV_{CEO} > 80V$
- $I_C = 1.5A$ Continuous Collector Current
- $R_{CE(SAT)} = 90m\Omega$ for a low equivalent On-Resistance
- 625mW Power dissipation
- h_{FE} specified up to 5A for high current gain hold up

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight 0.008 grams (approximate)

Applications

- DC-DC Modules
- Power Management Functions
- Motor control and drive functions
- CCFL Backlighting Inverters



Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

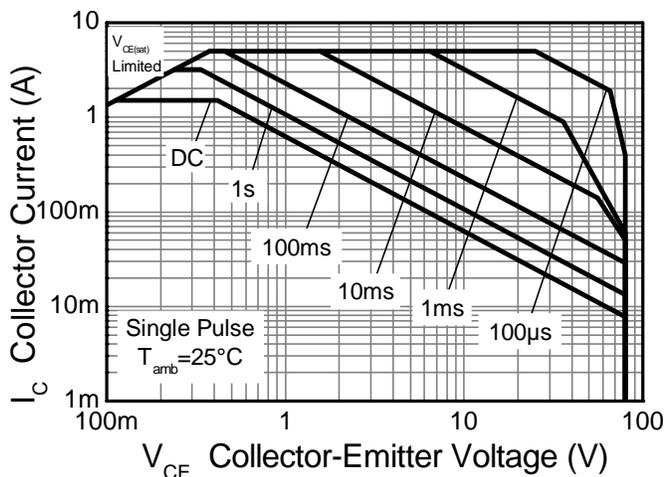
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	100	V
Collector-Emitter Voltage	V_{CEO}	80	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	1.5	A
Peak Pulse Current	I_{CM}	5	A
Base Current	I_B	500	mA

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

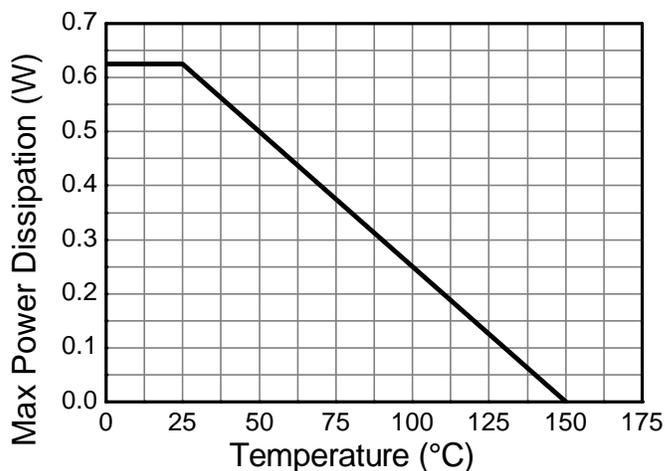
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P_D	625	mW
Power Dissipation (Note 7)	P_D	806	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Ambient (Note 7)	$R_{\theta JA}$	155	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Leads (Note 8)	$R_{\theta JL}$	194	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 7. Same as note 6, except the device is measured at $t \leq 5$ sec.
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

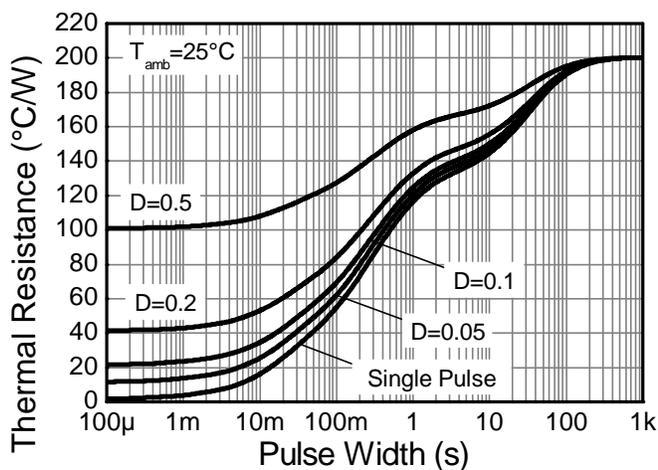
Thermal Characteristics and Derating information



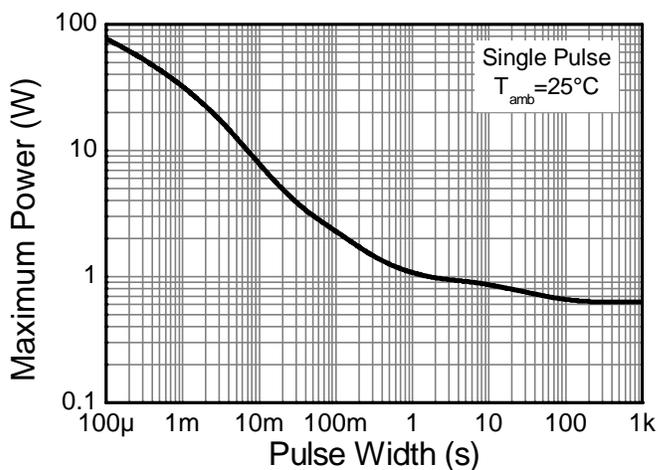
Safe Operating Area



Derating Curve



Transient Thermal Impedance



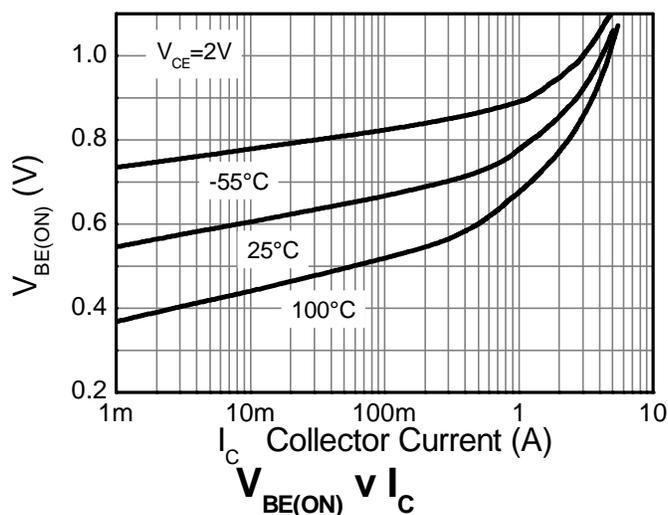
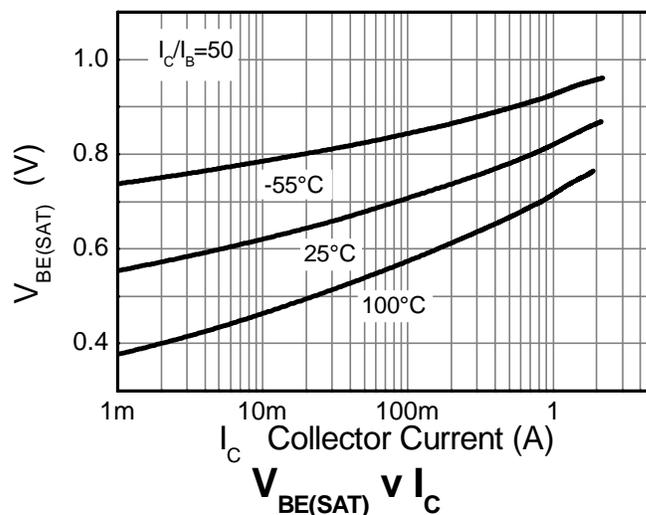
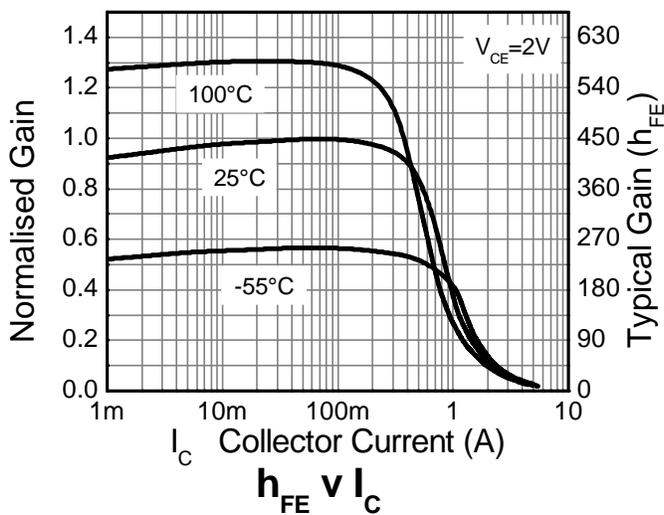
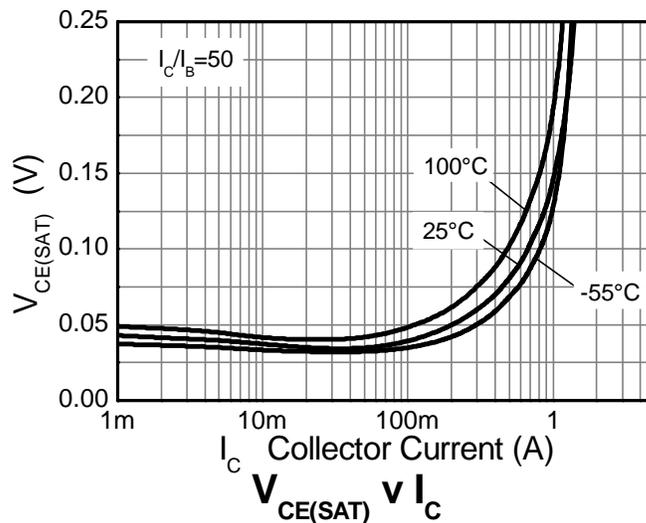
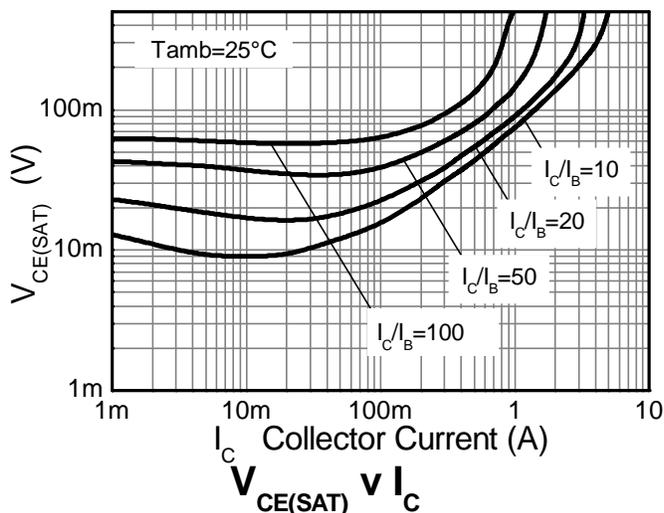
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

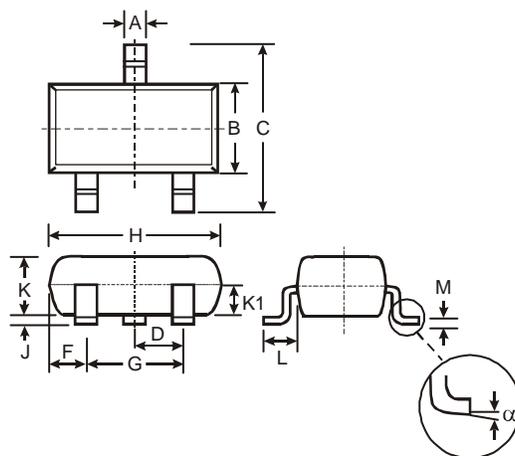
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	180	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	80	110	-	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8	-	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	-	-	100	nA	V _{CB} = 80V
Emitter Cut-off Current	I _{EBO}	-	-	100	nA	V _{EB} = 6.0V
Collector Emitter Cut-off Current	I _{CES}	-	-	100	nA	V _{CES} = 80V
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	200 300 110 60 20 -	450 450 170 90 30 10	- 900 - - - -	-	I _C = 10mA, V _{CE} = 2V I _C = 200mA, V _{CE} = 2V I _C = 1A, V _{CE} = 2V I _C = 1.5A, V _{CE} = 2V I _C = 3A, V _{CE} = 2V I _C = 5A, V _{CE} = 2V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	- - - -	15 45 145 160	20 60 185 200	mV	I _C = 0.1A, I _B = 10mA I _C = 0.5A, I _B = 50mA I _C = 1A, I _B = 20mA I _C = 1.5A, I _B = 20mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	0.86	1.0	V	I _C = 1.5A, I _B = 50mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(on)}	-	0.82	0.95	V	I _C = 1.5A, V _{CE} = 2V
Transition Frequency	f _T	100	160	-	MHz	I _C = 50mA, V _{CE} = 10V, f = 100MHz
Collector Output Capacitance	C _{obo}	-	11.5	18	pF	V _{CB} = 10V, f = 1MHz
Turn-On Time	t _(on)	-	86	-	ns	V _{CC} = 10V, I _C = 500mA, I _{B1} = -I _{B2} = 25mA
Turn-Off Time	t _(off)	-	1128	-	ns	

Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



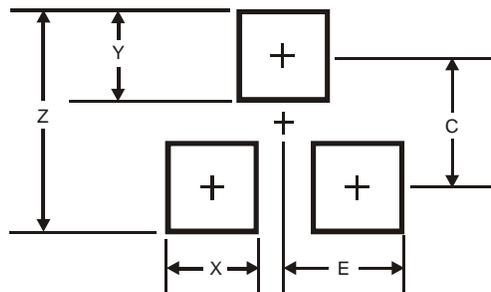
Package Outline Dimensions



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-

All Dimensions in mm

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35